

# ST2329I

## 2-bit dual-supply level translator with auto-direction feature and integrated pull-up

Target specification

### Features

- 18 Mbps (max.) data rate when driven by a totem pole driver
- 6.8 Mbps (max.) data rate when driven by an open drain pole driver
- Bidirectional level translation, without direction pin
- Wide V<sub>L</sub> voltage range of 1.65 V to 3.6 V
- Wide V<sub>CC</sub> voltage range of 1.80 V to 5.5 V
- Integrated 10 kΩ pull-up on both V<sub>CC</sub> and V<sub>L</sub> sides
- Power-down mode feature; when either supply is off, all I/Os are in high impedance
- Low quiescent current (max. 4 µA)
- Able to be driven by totem pole and open drain drivers
- 5.5 V tolerant enable pin
- ESD performance on all pins: ±2 kV HBM
- Small package and footprint QFN10 (1.8 x 1.4 mm) package

## Applications

- Low voltage system level translation
- Mobile phones and other mobile devices
- I<sup>2</sup>C level translation
- UART level translation



#### Table 1. Device summary

Order code	Package	Packing				
ST2329IQTR	QFN10 (1.8 x 1.4 mm)	Tape and reel (3000 parts per reel)				

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## 1 Description

ST2329I is a 2-bit dual-supply level translator which provides the level shifting capability to allow data transfer in a multi-voltage system. Externally applied voltages,  $V_{CC}$  and  $V_L$ , set the logic levels on either side of the device. It utilizes a transmission gate based design that allows bidirectional level translation without a control pin.

The ST2329I accepts V<sub>L</sub> from 1.65 V to 3.6 V and V<sub>CC</sub> from 1.80 V to 5.5 V, making it ideal for data transfer between low-voltage ASICs/PLD and higher voltage systems. This device has a tri-state output mode which can be used to disable all the I/Os.

The ST2329I supports power-down mode when V<sub>CC</sub> is grounded/floating and the device is disabled via the OE pin. The device has integrated 10 k $\Omega$  pull-ups on both sides.



## 2 Pin configuration

#### Figure 1. Pin configuration



#### Table 2. Pin description

QFN10 pin no	Symbol	Name and function
1, 2	I/O <sub>VL1</sub> to I/O <sub>VL2</sub>	Data inputs/outputs
8, 7	I/O <sub>VCC1</sub> to I/O <sub>VCC2</sub>	Data inputs/outputs
3	OE	Output enable input
6	GND	Ground
10	VL	Supply voltage
9	V <sub>CC</sub>	Supply voltage
4, 5	NC	No connect

#### Figure 2. Device block diagram



1. ST2329I has 2 channels. For simplicity, the diagram above shows only 1 channel.

2. When OE is LOW, all I/Os are in high impedance mode.







1. External pull-up resistors are optional. Only needed if a pull-up value lower than 10 k $\Omega$  is desired.

### 2.1 Supplementary notes

#### 2.1.1 Driver requirements

The ST2329I may be driven by an open drain or totem pole driver and the nature of the device output is "open drain". It must not be used to drive a pull-down resistor as the impedance of the output at HIGH state depends on the pull-up resistor placed at the I/Os.

As the device has pull-up resistors on both I/O<sub>VCC</sub> and I/O<sub>VL</sub> ports, the user needs to ensure that the driver is able to sink the required amount of current. For example, if the settings are  $V_{CC} = 5.5 \text{ V}$ ,  $V_L = 4.3 \text{ V}$ , and the pull-up resistor is 10 kΩ, then the driver must be able to sink at least (5.5 V / 10 kΩ) + (4.3 V / 10 kΩ)  $\approx$  1 mA and still meet  $V_{IL}$  requirements of ST2329I.

#### 2.1.2 Load driving capability

To support the open drain system, the one-shot transistor is turned on only during high transition at the output side. When it drives a high state, after the one-shot transistor turned off, only the pull-up resistor is able to maintain the state. In this case, the resistive load is not recommended.

#### 2.1.3 Power-off feature

In some applications where it might be required to turn off one of the power supplies powering up the level translator, the user may turn OFF the V<sub>CC</sub> only when the OE pin is low (device is disabled). There is no current consumption in V<sub>L</sub> due to floating gates or other causes, and the I/Os are in a high impedance state in this mode.



Enable	Bidirectional input/output							
OE	I/O <sub>VCC</sub>	I/O <sub>VL</sub>						
H <sup>(1)</sup>	H <sup>(2)</sup>	H <sup>(1)</sup>						
H <sup>(1)</sup>	L	L						
L	Z <sup>(3)</sup>	Z						

#### Table 3. Truth table

1. High level  $V_L$  power supply referred.

2. High level  $V_{CC}$  power supply referred.

3. Z = high impedance.

Symbol	Parameter	Value	Unit
VL	Supply voltage	-0.3 to 4.6	V
V <sub>CC</sub>	Supply voltage	-0.3 to 6.5	V
V <sub>OE</sub>	DC control input voltage	-0.3 to 6.5	V
V <sub>I/OVL</sub>	DC I/O <sub>VL</sub> input voltage (OE = GND or $V_L$ )	–0.3 to V <sub>L</sub> + 0.3	V
V <sub>I/OVCC</sub>	DC I/O <sub>VCC</sub> input voltage (OE = GND or $V_L$ )	-0.3 to V <sub>CC</sub> + 0.3	V
I <sub>IK</sub>	DC input diode current	-20	mA
I <sub>I/OVL</sub>	DC output current	±25	mA
II/OVCC	DC output current	±258	mA
I <sub>SCTOUT</sub>	Short-circuit duration, continuous	40	mA
PD	Power dissipation <sup>(1)</sup>	500	mW
T <sub>STG</sub>	Storage temperature	-65 to 150	°C
TL	Lead temperature (10 seconds)	300	°C
ESD	Electrostatic discharge protection (HBM)	±2	KV

1. 500 mW: 65 °C derated to 300 mW by 10 mW/°C: 65 °C to 85 °C.

#### Table 5. Recommended operating conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
VL	Supply voltage	1.65		3.6	V
V <sub>CC</sub> <sup>(1)</sup>	Supply voltage	1.8		5.5	V
V <sub>OE</sub>	Input voltage (OE output enable pin, V <sub>L</sub> power supply referred)	0		3.6	V
V <sub>I/OVL</sub>	I/O <sub>VL</sub> voltage	0		VL	V
V <sub>I/OVCC</sub>	I/O <sub>VCC</sub> voltage	0		V <sub>CC</sub>	V
TOP	Operating temperature	-40		85	°C
dt/dV	Input rise and fall time	0		1	ns/V

1.  $V_{CC}$  must be greater than  $V_L$ .

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	All typical valu		Test conditions Value									
Cumhal	Deverseter					05				Unit		
Symbol	Parameter	VL	v <sub>cc</sub>		1,	<sub>A</sub> = 25	°C	–40 to 85 °C				
		-			Min.	Тур.	Max.	Min.	Max.			
V		1.65			1.4			1.4				
	High level input	2.0	V <sub>L</sub> to 5.5		1.6			1.6				
V <sub>IHL</sub>	voltage on $V_L$ side	2.5		—	2.0			2.0		V		
(I/O <sub>VL</sub> )	(I/O <sub>VL</sub> )	3.0			2.4			2.4				
	3.6			2.8			2.8					
		1.65					0.3		0.3			
	Low level input	2.0					0.4		0.4			
V <sub>ILL</sub>	voltage on $V_L$ side	2.5	$V_L$ to 5.5	—			0.5		0.5			
	(I/O <sub>VL</sub> )	3.0					0.6		0.6			
		3.6					0.8		0.8			
	High level input voltage on V <sub>CC</sub> side (I/O <sub>VCC</sub> )		1.65			1.4		1.6		v		
			2.0			1.6		2.3				
V <sub>IHC</sub>		1.65 to	2.5			2.3		2.7				
IHC ▼ IHC		V <sub>CC</sub>	3.0			2.7		3.3				
				3.6			3.3		3.5			
			5.5			4.2		4.2				
					1.65				0.3			
			2.0				0.3					
N .	Low level input voltage on V <sub>CC</sub>	1.65 to	2.5				0.3			v		
V <sub>ILC</sub>	side (I/O <sub>VCC</sub> )	V <sub>CC</sub>	3.0	—			0.5			v		
			3.6				0.5					
			5.5				0.5					
		1.65			1.0			1.0		V		
		2.0			1.2			1.2				
V <sub>IH-OE</sub>	High level input voltage (OE)	2.5	$V_L$ to 5.5	—	1.4		Ī	1.4				
		3.0			1.6		Ī	1.6				
		3.6			2.0			2.0				

# Table 6.DC characteristics (over recommended operating conditions unless otherwise noted.<br/>All typical values are at $T_A = 25$ °C)



		Test conditions			Value					
Symbol	Parameter	v	V		T <sub>A</sub> = 25 °		25 °C ·		–40 to 85 °C	
		V <sub>L</sub> V <sub>CC</sub>			Min.	Тур.	Max.	Min.	Max.	
		1.65					0.33		0.33	V
		2.0					0.40		0.40	
V <sub>IL-OE</sub>	Low level input voltage (OE)	2.5	$V_L$ to 5.5	—			0.50		0.50	
	3.0					0.60		0.60		
		3.6					0.75		0.75	
V <sub>OLL</sub>	Low level output voltage (I/O <sub>VL</sub> )	1.65 to 3.6	$V_L$ to 5.5	IO=1.0 mA I/O <sub>VCC</sub> $\leq$ 0.15 V			0.40		0.40	۷
V <sub>OLC</sub>	Low level output voltage (I/O <sub>VCC</sub> )	1.65 to 3.6	$V_L$ to 5.5	IO=1.0 mA I/O <sub>VL</sub> $\leq$ 0.15 V			0.40		0.40	V
I <sub>OE</sub>	Control input leakage current (OE)	1.65 to 3.6	$V_L$ to 5.5	$V_{OE} = GND \text{ or } V_L$			±0.1		±0.1	μA
I <sub>IO_LKG</sub>	High impedance leakage current (I/O <sub>VL</sub> , I/O <sub>VCC</sub> )	1.65 to 3.6	$V_L$ to 5.5	OE = GND			±0.1		±0.1	μA
IQVCC	Quiescent supply current V <sub>CC</sub>	1.65 to 3.6	$V_L$ to 5.5	Only pull-up resistor connected to I/O		3	3.5		6	μA
I <sub>QVL</sub>	Quiescent supply current V <sub>L</sub>	1.65 to 3.6	$V_L$ to 5.5	Only pull-up resistor connected to I/O		0.01	0.1		1	μΑ
I <sub>Z-VCC</sub>	High impedance quiescent supply current V <sub>CC</sub>	1.65 to 3.6	$V_L$ to 5.5	OE = GND; only pull-up resistor connected to I/O		3	3.5		6	μΑ
I <sub>Z-VL</sub>	High impedance quiescent supply current V <sub>L</sub>	1.65 to 3.6	$V_L$ to 5.5	OE = GND; only pull-up resistor connected to I/O		0.01	0.1		1	μA

Table 6.DC characteristics (over recommended operating conditions unless otherwise noted.<br/>All typical values are at  $T_A = 25$  °C) (continued)



## 2.2 AC characteristics (device driven by open drain driver)

Table 7.For test conditions:  $V_L = 1.65$  to 1.8 V (load  $C_L = 15 \text{ pF}$ ;  $R_{up} = 4.7 \text{ k}\Omega$ ;driver  $t_r = t_f \le 2 \text{ ns}$ ) overtemperature range -40 °C to 85 °C

Symbol	Parameter		V <sub>CC</sub> = 1.8 - 2.5 V		V <sub>CC</sub> = 2.7 - 3.6 V		V <sub>CC</sub> = 4.3 - 5.5 V		Unit
Symbol			Min.	Max.	Min.	Max.	Min.	Max.	Onit
t <sub>RVCC</sub>	Rise time I/O <sub>VCC</sub>			80		60		45	ns
t <sub>FVCC</sub>	Fall time I/O <sub>VCC</sub>			23.2		33.9		53.3	ns
t <sub>RVL</sub>	Rise time I/O <sub>VL</sub>			60		45		35	ns
t <sub>FVL</sub>	Fall time I/O <sub>VL</sub>			16.4		17.6		16.9	ns
t <sub>I/OVL-VCC</sub>	Propagation delay time I/O <sub>VL-LH</sub> to I/O <sub>VCC-LH</sub> I/O <sub>VL-HL</sub> to I/O <sub>VCC-HL</sub>	t <sub>PLH</sub>		3.4		2			ns
		t <sub>PLH</sub>		13.9		19.1		30.2	ns
	Propagation delay time	t <sub>PLH</sub>		2		2		2.6	ns
t <sub>l/OVCC-VL</sub>	I/O <sub>VCC-LH</sub> to I/O <sub>VL-LH</sub> I/O <sub>VCC-HL</sub> to I/O <sub>VL-HL</sub>	t <sub>PLH</sub>		8.6		9		9.5	ns
t <sub>PZL</sub> t <sub>PZH</sub>	Output enable and disable time	En		10		10		10	ns
t <sub>PLZ</sub> t <sub>PHZ</sub>		Dis		40		40		40	ns
D <sub>R</sub>	Data rate <sup>(1)</sup>			1.8		2.2		3.4	MHz

The data rate is guaranteed based on the condition that the output I/O signal rise/fall time is less than 15% of the input I/O signal period; the input I/O signal is at 50% duty cycle and the output I/O signal duty cycle deviation is not less than 30%. Note that the R<sub>up</sub> of 4.7 kΩ is an effective R pull-up value. Since the device has an integrated 10 kΩ pull-up resistor, an effective value of 4.7 kΩ is obtained by adding an external 8.9 kΩ pull-up resistor.

Table 8.	For test conditions: $V_L$ = 2.5 to 2.7 V (load $C_L$ = 15 pF; $R_{up}$ = 4.7 k $\Omega$ ;
	driver $t_r = t_f \le 2$ ns) overtemperature range –40 °C to 85 °C

Symbol	Parameter		V <sub>CC</sub> = 2	2.7 - 3.6 V	V <sub>CC</sub> = 4.	3 - 5.5 V	Unit
Symbol			Min.	Max.	Min.	Max.	
t <sub>RVCC</sub>	Rise time I/O <sub>VCC</sub>			70		50	ns
t <sub>FVCC</sub>	Fall time I/OV <sub>VCC</sub>			14.8		19.1	ns
t <sub>RVL</sub>	Rise time I/O <sub>VL</sub>			50		35	ns
t <sub>FVL</sub>	Fall time I/O <sub>VL</sub>			9.8		10	ns
	Propagation delay time	t <sub>PLH</sub>		2		2	ns
t <sub>l/OVL-VCC</sub>	I/O <sub>VL-LH</sub> to I/O <sub>VCC-LH</sub> I/O <sub>VL-HL</sub> to I/O <sub>VCC-HL</sub>	t <sub>PLH</sub>		8.2		11.6	ns
_	Propagation delay time	t <sub>PLH</sub>		2		2	ns
t <sub>l/OVCC-VL</sub>	I/O <sub>VCC-LH</sub> to I/O <sub>VL-LH</sub> I/O <sub>VCC-HL</sub> to I/O <sub>VL-HL</sub>	t <sub>PLH</sub>		5.3		5.9	ns
t <sub>PZL</sub> t <sub>PZH</sub>	Output enable and disable time	En		6		6	ns
t <sub>PLZ</sub> t <sub>PHZ</sub>	t <sub>PLZ</sub> t <sub>PHZ</sub>			40		40	ns
D <sub>R</sub>	Data rate <sup>(1)</sup>			2.2		3.0	MHz

The data rate is guaranteed based on the condition that the output I/O signal rise/fall time is less than 15% of the input I/O signal period; the input I/O signal is at 50% duty cycle and the output I/O signal duty cycle deviation is not less than 30%. Note that the R<sub>up</sub> of 4.7 kΩ is an effective R pull-up value. Since the device has an integrated 10 kΩ pull-up resistor, an effective value of 4.7 kΩ is obtained by adding an external 8.9 kΩ pull-up resistor.



Symbol	Parameter	Parameter			Unit
Symbol	Farameter		Min.	Max.	Unit
t <sub>RVCC</sub>	Rise time I/O <sub>VCC</sub>			55	ns
t <sub>FVCC</sub>	Fall time I/O <sub>VCC</sub>			17.2	ns
t <sub>RVL</sub>	Rise time I/O <sub>VL</sub>			40	ns
t <sub>FVL</sub>	Fall time I/O <sub>VL</sub>	Fall time I/O <sub>VL</sub>		9.7	ns
	Propagation delay time	t <sub>PLH</sub>		2	ns
t <sub>I/OVL-VCC</sub>	I/O <sub>VL-LH</sub> to I/O <sub>VCC-LH</sub> I/O <sub>VL-HL</sub> to I/O <sub>VCC-HL</sub>	t <sub>PLH</sub>		10.6	ns
	Propagation delay time	t <sub>PLH</sub>		2	ns
ti/ovcc-vL	I/O <sub>VCC-LH</sub> to I/O <sub>VL-LH</sub> I/O <sub>VCC-HL</sub> to I/O <sub>VL-HL</sub>	t <sub>PLH</sub>		4.8	ns
		En		6	ns
t <sub>PZL</sub> t <sub>PZH</sub> t <sub>PLZ</sub> t <sub>PHZ</sub>	Output enable and disable time	Dis		40	ns
DR	Data rate <sup>(1)</sup>			3.0	MHz

#### For test conditions: V<sub>L</sub> = 2.7 to 3.6 V (load C<sub>L</sub> = 15 pF; R<sub>up</sub> = 4.7 kΩ; driver t<sub>r</sub> = t<sub>f</sub> $\leq$ 2 ns) overtemperature range –40 °C to 85 °C Table 9.

The data rate is guaranteed based on the condition that the output I/O signal rise/fall time is less than 15% of the input I/O signal period; the input I/O signal is at 50% duty cycle and the output I/O signal duty cycle deviation is not less than 30%. Note that the R<sub>up</sub> of 4.7 kΩ is an effective R pull-up value. Since the device has an integrated 10 kΩ pull-up resistor, an effective value of 4.7 kΩ is obtained by adding an external 8.9 kΩ pull-up resistor. 1.



## 2.3 AC characteristics (device driven by totem pole driver)

Table 10.For test conditions:  $V_L = 1.65$  to 1.8 V (load  $C_L = 15 \text{ pF}$ ;  $R_{up} = 10 \text{ k}\Omega$ ;driver  $t_r = t_f \le 2 \text{ ns}$ ) overtemperature range -40 °C to 85 °C

Symbol	Symbol Parameter .		V <sub>CC</sub> = 1.8 - 2.5 V		$V_{CC} = 2.7 - 3.6 V$		$V_{CC} = 4.3 - 5.5 V$		Unit
Symbol			Min.	Max.	Min.	Max.	Min.	Max.	Omt
t <sub>RVCC</sub>	Rise time I/O <sub>VCC</sub>			7.2		4.6		1.4	ns
t <sub>FVCC</sub>	Fall time I/O <sub>VCC</sub>			23.2		33.9		53.3	ns
t <sub>RVL</sub>	Rise time I/O <sub>VL</sub>			5.9		5.7		5.5	ns
t <sub>FVL</sub>	Fall time I/O <sub>VL</sub>			16.4		17.6		16.9	ns
	Propagation delay time	t <sub>PLH</sub>		5.5		4.1		3.6	ns
t <sub>l/OVL-VCC</sub>	I/O <sub>VL-LH</sub> to I/O <sub>VCC-LH</sub> I/O <sub>VL-HL</sub> to I/O <sub>VCC-HL</sub>	t <sub>PLH</sub>		13.9		19.1		30.2	ns
_	Propagation delay time	t <sub>PLH</sub>		4.5		3.9		3.6	ns
t <sub>l/OVCC-VL</sub>	VL I/O <sub>VCC-LH</sub> to I/O <sub>VL-LH</sub> I/O <sub>VCC-HL</sub> to I/O <sub>VL-HL</sub>			8.6		9.0		9.5	ns
t <sub>PZL</sub> t <sub>PZH</sub>	Output enable and disable time	En		10		10		10	ns
t <sub>PLZ</sub> t <sub>PHZ</sub>		Dis		40		40		40	ns
D <sub>R</sub>	Data rate <sup>(1)</sup>			6.4		4.5		3.0	MHz

The data rate is guaranteed based on the condition that the output I/O signal rise/fall time is less than 15% of the input I/O signal period; the input I/O signal is at 50% duty cycle and the output I/O signal duty cycle deviation is not less than 30%. Note that the R<sub>up</sub> of 4.7 kΩ is an effective R pull-up value. Since the device has an integrated 10 kΩ pull-up resistor, an effective value of 4.7 kΩ is obtained by adding an external 8.9 kΩ pull-up resistor.

Table 11.For test conditions:  $V_L = 2.5$  to 2.7 V (load  $C_L = 15 \text{ pF}$ ;  $R_{up} = 10 \text{ k}\Omega$ ;<br/>driver  $t_r = t_f \le 2 \text{ ns}$ ) overtemperature range -40 °C to 85 °C

Symbol	Parameter		V <sub>CC</sub> = 2	2.7 - 3.6 V	V <sub>CC</sub> = 4	.3 - 5.5 V	Unit
Symbol			Min.	Max.	Min.	Max.	
t <sub>RVCC</sub>	Rise time I/O <sub>VCC</sub>			3.8		2.8	ns
t <sub>FVCC</sub>	Fall time I/O <sub>VCC</sub>			14.8		19.1	ns
t <sub>RVL</sub>	Rise time I/O <sub>VL</sub>			3.3		3.2	ns
t <sub>FVL</sub>	Fall time I/O <sub>VL</sub>			9.8		10.0	ns
	Propagation delay time	t <sub>PLH</sub>		3.2		2.8	ns
t <sub>l/OVL</sub> -VCC	/L-VCC I/O <sub>VL-LH</sub> to I/O <sub>VCC-LH</sub> I/O <sub>VL-HL</sub> to I/O <sub>VCC-HL</sub>			8.2		11.6	ns
_	Propagation delay time	t <sub>PLH</sub>		2.6		2.0	ns
t <sub>l/OVCC-VL</sub>	I/O <sub>VCC-LH</sub> to I/O <sub>VL-LH</sub> I/O <sub>VCC-HL</sub> to I/O <sub>VL-HL</sub>	t <sub>PLH</sub>		5.3		5.9	ns
t <sub>PZL</sub> t <sub>PZH</sub>	Output enable and disable time	En		6		6	ns
t <sub>PLZ</sub> t <sub>PHZ</sub>				40		40	ns
DR	Data rate <sup>(1)</sup>			9		6.8	MHz

The data rate is guaranteed based on the condition that the output I/O signal rise/fall time is less than 15% of the input I/O signal period; the input I/O signal is at 50% duty cycle and the output I/O signal duty cycle deviation is not less than 30%. Note that the R<sub>up</sub> of 4.7 kΩ is an effective R pull-up value. Since the device has an integrated 10 kΩ pull-up resistor, an effective value of 4.7 kΩ is obtained by adding an external 8.9 kΩ pull-up resistor.



Symbol	Paramotor	Parameter			Unit
Symbol	Faranieler		Min.	Max.	Unit
t <sub>RVCC</sub>	Rise time I/O <sub>VCC</sub>			2.9	ns
t <sub>FVCC</sub>	Fall time I/O <sub>VCC</sub>			17.2	ns
t <sub>RVL</sub>	Rise time I/O <sub>VL</sub>			3.0	ns
t <sub>FVL</sub>	Fall time I/O <sub>VL</sub>	Fall time I/O <sub>VL</sub>		9.7	ns
	Propagation delay time	t <sub>PHL</sub>		2.7	ns
t <sub>l/OVL-VCC</sub>	-VCC I/O <sub>VL-LH</sub> to I/O <sub>VCC-LH</sub> I/O <sub>VL-HL</sub> to I/O <sub>VCC-HL</sub>			10.6	ns
	Propagation delay time	t <sub>PHL</sub>		1.9	ns
ti/ovcc-vL	I/O <sub>VCC-LH</sub> to I/O <sub>VL-LH</sub> I/O <sub>VCC-HL</sub> to I/O <sub>VL-HL</sub>	t <sub>PHL</sub>		4.8	ns
t <sub>PZL</sub> t <sub>PZH</sub>	Output anable and disable time	En		6	ns
t <sub>PLZ</sub> t <sub>PHZ</sub>	Output enable and disable time	Dis		40	ns
D <sub>R</sub>	Data rate <sup>(1)</sup>			7.2	MHz

# Table 12.For test conditions: $V_L = 2.7$ to 3.6 V (load $C_L = 15 \text{ pF}$ ; $R_{up} = 10 \text{ k}\Omega$ ;driver $t_r = t_f \le 2 \text{ ns}$ ) overtemperature range -40 °C to 85 °C

The data rate is guaranteed based on the condition that the output I/O signal rise/fall time is less than 15% of the input I/O signal period; the input I/O signal is at 50% duty cycle and the output I/O signal duty cycle deviation is not less than 30%.

Note that the R<sub>up</sub> of 4.7 k $\Omega$  is an effective R pull-up value. Since the device has an integrated 10 k $\Omega$  pull-up resistor, an effective value of 4.7 k $\Omega$  is obtained by adding an external 8.9 k $\Omega$  pull-up resistor.





#### Table 13. Test circuit

Test	Switch				
1631	Driving I/O <sub>VL</sub>	Driving I/O <sub>VCC</sub>	Open drain driving		
t <sub>PLH</sub> , t <sub>PHL</sub>	Open	Open	Open		

Note: The pull-up resistors shown in the above test circuit are optional and are only needed if total pull-up on either end of the level translator needs to be lower than 10 k $\Omega$ . In applications where 10 k $\Omega$  is sufficient, the external pull-up resistor is not required.

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	Driving	g I/O <sub>VL</sub>	/L Driving I/O <sub>VCC</sub>				
Symbol	$ \begin{array}{ c c c c c } \hline 1.8 \ V \leq V_L \leq V_{CC} \\ \leq 2.5 \ V \\ \hline \end{array} \begin{array}{ c c c c c } \hline 3.3 \ V \leq V_L \leq V_{CC} \\ \leq 5.0 \ V \\ \hline \end{array} \end{array} $		$\begin{array}{c} \textbf{1.8 V} \leq \textbf{V_L} \leq \textbf{V_{CC}} \\ \leq \textbf{2.5 V} \end{array}$	$\begin{array}{c} \textbf{3.3 V} \leq \textbf{V}_{L} \leq \textbf{V}_{CC} \\ \leq \textbf{5.0 V} \end{array}$			
V <sub>IH</sub>	VL	VL	V <sub>CC</sub>	V <sub>CC</sub>			
V <sub>IM</sub>	50% V <sub>L</sub>	50% V <sub>L</sub>	50% V <sub>CC</sub>	50% V <sub>CC</sub>			
V <sub>OM</sub>	50% V <sub>CC</sub>	50% V <sub>CC</sub>	50% V <sub>CC</sub>	50% V <sub>CC</sub>			
V <sub>X</sub>	V <sub>OL</sub> +15 V	V <sub>OL</sub> +0.3 V	V <sub>OL</sub> +0.15 V	V <sub>OL</sub> +0.3 V			
V <sub>Y</sub>	V <sub>OH</sub> –15 V	V <sub>OH</sub> –0.3 V	V <sub>OH</sub> –0.15 V	V <sub>OH</sub> –0.3 V			

Table 14. Waveform symbol value









## 3 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at *www.st.com*. ECOPACK is an ST trademark.







Symbol	millimeters			inches			Note
Symbol	Тур.	Min.	Max.	Тур.	Min.	Max.	
A	0.5	0.45	0.55	0.02	0.018	0.022	
A1	0.02	0	0.05	0.001	0	0.002	
A3	0.13			0.005			
b	0.2	0.15	0.25	0.008	0.006	0.01	
D	1.8	1.75	1.85	0.071	0.069	0.073	
E	1.4	1.35	1.45	0.055	0.053	0.057	
e	0.4			0.016			
L	0.4	0.35	0.45	0.016	0.014	0.018	

Table 15.Mechanical data for QFN10 (1.8 x 1.4 x 0.5 mm) - 0.40 mm pitch







#### Figure 9. Carrier tape for QFN10 (1.8 x 1.4 x 0.5 mm) - 0.40 mm pitch





Figure 10. Reel information for QFN10 (1.8 x 1.4 x 0.5 mm) - 0.40 mm pitch - back view







# 4 Revision history

#### Table 16. Document revision history

Date	Revision	Changes
02-Mar-2011	1	Initial release.



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